

60V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8 (Type UX)

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _C = +25°C
60V	18mΩ @ V _{GS} = 10V	35A
	20mΩ @ V _{GS} = 4.5V	34A

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

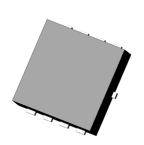
Features and Benefits

- Low R_{DS(ON)} Ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

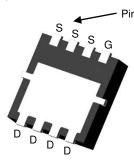
Mechanical Data

- Case: PowerDI[®]3333-8 (Type UX)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.030 grams (Approximate)

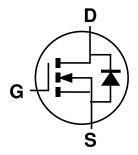
PowerDI3333-8 (Type UX)







Bottom View



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN6017SFV-7	PowerDI3333-8 (Type UX)	2,000/Tape & Reel
DMN6017SFV-13	PowerDI3333-8 (Type UX)	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



N67 = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 18 = 2018)
WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	60	V	
Gate-Source Voltage	V_{GSS}	±20	V	
Continuous Drain Current (Note 7) $V_{GS} = 10V$ $T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$		I _D	35 28	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	140	Α	
Maximum Continuous Body Diode Forward Current (Note 7)	Is	20	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	I _{SM}	140	Α	
Avalanche Current, L = 0.1mH (Note 8)	I _{AS}	25	Α	
Avalanche Energy, L = 0.1mH (Note 8)	E _{AS}	32	mJ	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		P_{D}	1.0	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ hetaJA}$	126	°C/W
Total Power Dissipation (Note 6)		P_{D}	2.0	W
Thermal Resistance, Junction to Ambient (Note 6) Steady State		$R_{ hetaJA}$	62	°C/W
Thermal Resistance, Junction to Case (Note 7)		$R_{ heta JC}$	3.7	3G/VV
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(TH)}	1	_	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		_	12	18	mΩ	$V_{GS} = 10V, I_D = 6A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	13	20		$V_{GS} = 4.5V, I_D = 4A$	
Diode Forward Voltage	V _{SD}	_	0.7	1	V	$V_{GS} = 0V$, $I_S = 1A$	
DYNAMIC CHARACTERISTICS (Note 10)	-						
Input Capacitance	C _{iss}		2711	_	рF	$V_{DS} = 15V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	_	152	_	рF		
Reverse Transfer Capacitance	C _{rss}	_	126	_	pF		
Gate Resistance	R_g	_	1.4	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Q_g	_	26	_	nC		
Total Gate Charge (V _{GS} = 10V)	Qq	_	55	_	nC	V _{DS} = 48V, I _D = 6A	
Gate-Source Charge	Qgs	_	6.2	_	nC		
Gate-Drain Charge	Q _{qd}	_	8.5	_	nC		
Turn-On Delay Time	t _{D(ON)}	_	4.9	_	ns		
Turn-On Rise Time	t _R	_	5.4	_	ns	$V_{DD} = 30V, V_{GS} = 10V,$ $R_G = 3.3\Omega, I_D = 6A$	
Turn-Off Delay Time	t _{D(OFF)}	_	38.2	_	ns		
Turn-Off Fall Time	t _F	_	11	_	ns		
Reverse Recovery Time	t _{RR}	_	16.6	_	ns		
Reverse Recovery Charge	Q _{RR}	-	10.3	_	nC		

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
- 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_{J} = +25$ °C.
- Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.





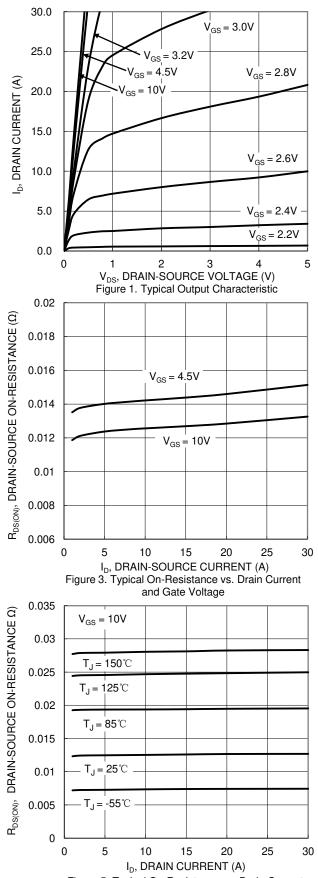
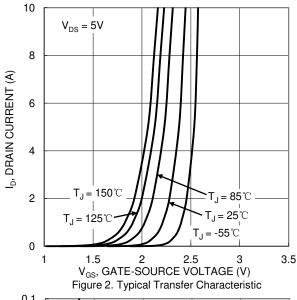
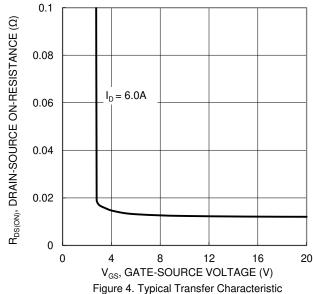


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature





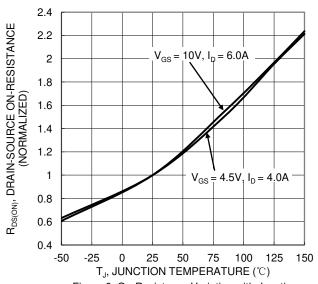


Figure 6. On-Resistance Variation with Junction Temperature





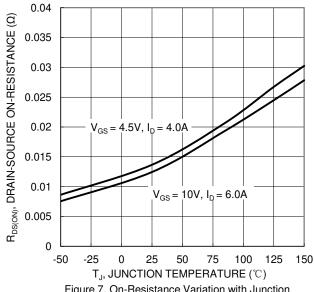
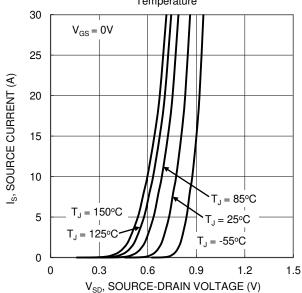
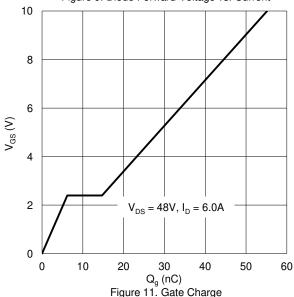


Figure 7. On-Resistance Variation with Junction Temperature



 ${
m V}_{
m SD},$ SOURCE-DRAIN VOLTAGE (V) Figure 9. Diode Forward Voltage vs. Current



2.2 $V_{\text{GS(TH)}},$ GATE THRESHOLD VOLTAGE (V) 2 1.8 $I_D = 1mA$ 1.6 1.4 $I_{D} = 250 \mu A$ 1.2 1 8.0 0.6 0.4 -50 -25 0 25 50 75 100 125 150 T_J , JUNCTION TEMPERATURE ($^{\circ}$ C)

Figure 8. Gate Threshold Variation vs. Junction Temperature

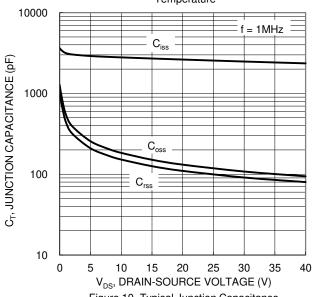
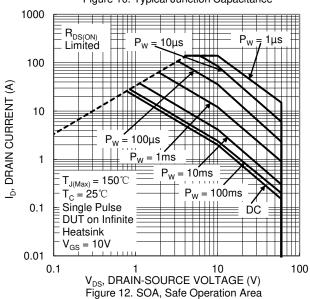


Figure 10. Typical Junction Capacitance





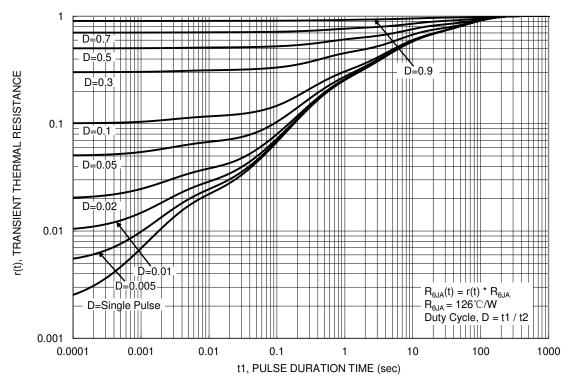


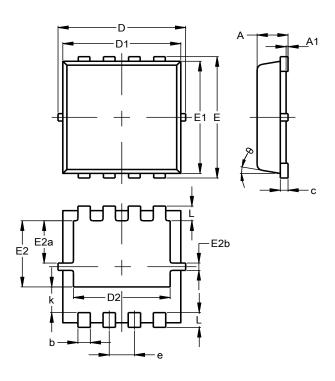
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)

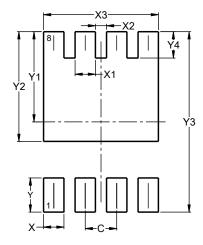


PowerDI3333-8					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
C	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E2a	0.95	1.35	1.15		
E2b	0.10	0.30	0.20		
е	0.65 BSC				
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)



Dimensions	Value (in mm)		
С	0.650		
X	0.420		
X1	0.420		
X2	0.230		
Х3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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